Erratum: Pfaffian Formalism for Higher-Order Topological Insulators
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Below Eq. (6) on page 3 of the original Letter, the statement “ $M(\mathbf{k})$ is antisymmetric $M^T(\mathbf{k}) = -M(\mathbf{k})$ for every $\mathbf{k}$ in the BZ” should be replaced by “ $M(\mathbf{k})$ is antisymmetric $M^T(\mathbf{k}) = -M(\mathbf{k})$ for every $\mathbf{k}$ invariant under a C_4 rotation ($C_4\mathbf{k} = \mathbf{k}$, the straight lines $Z\bar{Z}$ and $A\bar{A}$ in Fig. 2).” Similarly, in the Supplemental Material of original Letter, the proof of the antisymmetry of M should be restricted to C_4 -invariant $\mathbf{k}$ points. Because the matrix M is only defined and utilized at C_4 -invariant $\mathbf{k}$ points, this revision does not affect any conclusions and proofs reported in the original Letter.